

# isc N-Channel MOSFET Transistor

# IPW65R150CFD

### • FEATURES

- Static drain-source on-resistance: R<sub>DS</sub>(on)≤150mΩ
- Enhancement mode:
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## DESCRITION

· Fast Switching

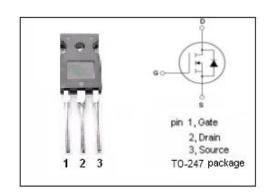


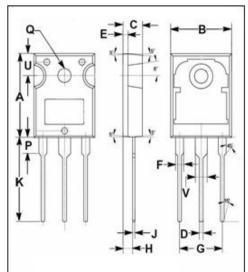
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	650	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	22.4	А
I <sub>DM</sub>	Drain Current-Single Pulsed	72	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	195.3	W
Tj	Max. Operating Junction Temperature	150	$^{\circ}\!\mathbb{C}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	0.64	°C/W
Rth(j-a)	Channel-to-ambient thermal resistance		°C/W





1	mm		
DIM	MIN	MAX	
Α	19.80	20.20	
В	15.40	15.80	
C	4.90	5.10	
D	0.90	1.10	
E	1.40	1.60	
F	1.90	2.10	
G	10.80	11.00	
Н	2.40	2.60	
J	0.50	0.70	
K	19.50	20.50	
P	3.90	4.10	
Q	3.30	3.50	
U	5.20	5.40	
٧	2.90	3.10	



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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =1mA	650			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	VDS=VGS; I <sub>D</sub> =0.9mA	3.5		4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =9.3 A			150	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = 20V; V <sub>DS</sub> =0V			0.1	mA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =650V; V <sub>GS</sub> = 0V			1	μА
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> =14A, V <sub>GS</sub> = 0V				V

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